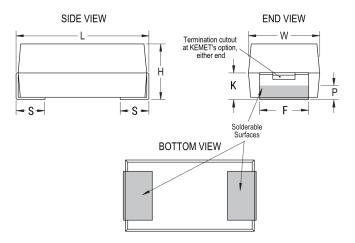


Aliases (T429H157K010AC4250)

T429 CWR29, Tantalum, MnO2 Tantalum, Military/High Reliability, 150 uF, 10%, 10 VDC, SMD, MnO2, Molded, Military Equivalent, Low ESR, A (Non-ER), 180 mOhms, 7238, Height Max = 3.17mm



Click here for the 3D model.

Dimensions	
Footprint	7238
L	7.24mm +/-0.38mm
W	3.81mm +/-0.38mm
Н	2.79mm +/-0.38mm
S	1.27mm +0.25/-0.13mm
F	3.68mm +0.13/-0.51mm
K	1.52mm MIN
Р	0.76mm MIN

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Informati	on
Series	T429 CWR29
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Military Equivalent, Low ESR
RoHS	No
Prop 65	▲ WARNING: Cancer and reproductive harm - http://www.p65warnings.ca.gov.
SCIP Number	652b281f-d242-4453-bc44-0655d646cec3
Termination	Hot Solder Dipped
Qualifications	MIL-PRF-55365/11, CWR29 Style
AEC-Q200	No
Component Weight	349.01 mg
Notes	Note: When Option C Is Selected For Lead Material, Add An Additional 0.38mm To The Tolerances For "L", "W", "H", "K" ,"F" And "S".
MSL	1

Specifications	
Capacitance	150 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	10% 120Hz 25C
Failure Rate	A (Non-ER)
Resistance	0.18 Ohms (100kHz 25C)
Leakage Current	15 uA (5min 25°C)
Testing and Reliability	Surge Testing At 25C After Weibull

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

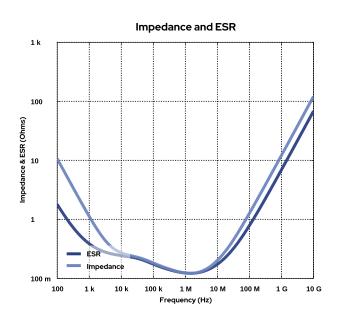


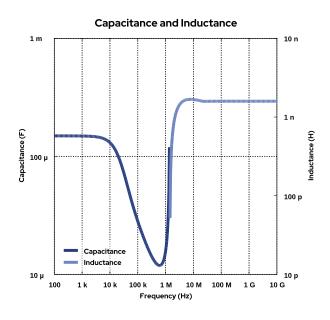
Aliases (T429H157K010AC4250)

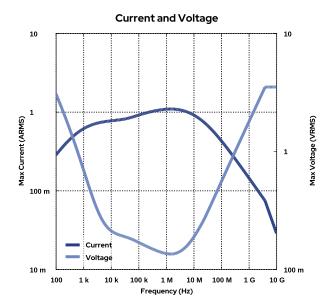
T429 CWR29, Tantalum, MnO2 Tantalum, Military/High Reliability, 150 uF, 10%, 10 VDC, SMD, MnO2, Molded, Military Equivalent, Low ESR, A (Non-ER), 180 mOhms, 7238, Height Max = 3.17mm

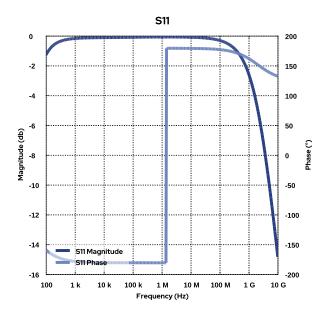
## **Simulations**

For the complete simulation environment please visit K-SIM.





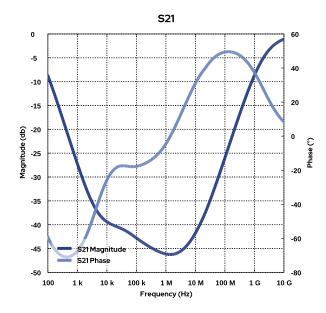






Aliases (T429H157K010AC4250)

T429 CWR29, Tantalum, MnO2 Tantalum, Military/High Reliability, 150 uF, 10%, 10 VDC, SMD, MnO2, Molded, Military Equivalent, Low ESR, A (Non-ER), 180 mOhms, 7238, Height Max = 3.17mm





Aliases (T429H157K010AC4250)

T429 CWR29, Tantalum, MnO2 Tantalum, Military/High Reliability, 150 uF, 10%, 10 VDC, SMD, MnO2, Molded, Military Equivalent, Low ESR, A (Non-ER), 180 mOhms, 7238, Height Max = 3.17mm

#### These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.

# 单击下面可查看定价,库存,交付和生命周期等信息

# >>KEMET(基美)